

L Number	Hits	Search Text	DB	Time stamp
1	0	microcircuit and stacked and encapsulant and encasing and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:16
2	0	microcircuit and stacked and encapsulant and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:17
3	0	microcircuit and PEM and encapsulant and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:17
4	0	PEM and encapsulant and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:17
5	0	PEM and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:17
6	2601	PEM	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:17
7	80	(PEM) and encapsulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:18
8	29	(PEM) and encapsulation and removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:18
9	394917	(PEM) and removing insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:20
10	0	(PEM) and removing near insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:20

11	0	(PEM) and removing near encapsulant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:21
12	2	(PEM) and removing same encapsulant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:30
13	0	20020119605.URPN.	USPAT	2003/03/12 12:22
14	21	("4017495" "4118861" "4490496" "4729062" "4826756" "4830922" "4902769" "4920639" "4991286" "5274913" "5381304" "5405807" "5434751" "5512613" "5560934" "5600181" "5641546" "5685071" "5828126" "5858943" "6111323").PN.	USPAT	2003/03/12 12:22
15	41	("3801880" "3864426" "4012832" "4370292" "4529755" "4604444" "4626556" "4632798" "4663190" "4729062" "4738892" "4983683" "4985751" "5037779" "5043211" "5061657" "5064895" "5072874" "5120678" "5128204" "5140068" "5160786" "5199163" "5250848" "5264520" "5274913" "5286572" "5298548" "5300625" "5313365" "5326413" "5371328" "5381304" "5434751" "5457149" "5460767" "5471096" "5474620" "5498689" "5821456" "5863664").PN.	USPAT	2003/03/12 12:24
16	0	(PEM) and removing and grinding near encapsulant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:31
17	0	(PEM) and removing and grinding near (encapsulant or insulation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:32
18	6	removing and grinding near (encapsulant or insulation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:33
19	1	IC and grinding near (encapsulant or insulation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:36

20	0	8153696.URPN.	USPAT	2003/03/12 12:34
21	1	1996-331608.NRAN.	DERWENT	2003/03/12 12:34
22	552166	29/\$.ccls. grinding near encapsulant or insulation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:36
23	166292	29/\$.ccls. grinding near (encapsulant or insulation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:37
24	2	29/\$.ccls. and grinding near (encapsulant or insulation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:37
25	0	"Albert et al".inv.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:38
26	28	29/840.ccls. and microcircuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:39
27	3	29/840.ccls. and microcircuit and encapsulant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:42
28	0	20020126459.URPN.	USPAT	2003/03/12 12:42
29	2	"Stackable microcircuit layer "	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:43
30	1	"Stackable microcircuit " and 174/52.2.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:43
31	4077	"Stackable microcircuit layer "and (361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:44

Class + Sub

32	0	"Stackable microcircuit layer" and (361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls. and grinding and removing and encasing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:45
33	1	"Stackable microcircuit layer" and (361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls. and grinding and removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:45
34	1	"Stackable microcircuit layer" and (361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls. and removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:45
35	23	microcircuit and (361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls. and removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 12:48
36	4	(361/743;29/830 ;29/840 ;29/841 ;361/735 ;361/746).ccls. and encapsulant near removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:07
37	17	("3903590" "4466181" "4783695" "4835704" "4878991" "4933042" "5019946" "5048179" "5091769" "5108825" "5139969" "5144747" "5151776" "5154793" "5155068" "5161093" "5255431").PN.	USPAT	2003/03/12 12:52
38	8	("3702464" "4532419" "4603249" "4725924" "4774633" "4803542" "4822989" "4931853").PN.	USPAT	2003/03/12 13:03
39	10	("5207864" "5386624" "5406025" "5483421" "5638597" "5739053" "5785234" "5813115" "5816478" "5873161").PN.	USPAT	2003/03/12 13:05
40	6	("3676745" "5323295" "5365403" "5367439" "5467251" "5644103").PN.	USPAT	2003/03/12 13:06
41	60	encapsulant near removal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:10
42	0	20010039120.URPN.	USPAT	2003/03/12 13:08
43	14	encapsulant near remove and pad and wire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:13

44	15	("4281031" "4344809" "4359360" "4826556" "5252179" "5254237" "5271798" "5321222" "5350737" "5521360" "5552112" "5648038" "5766496" "6011249" "6211499").PN.	USPAT	2003/03/12 13:12
45	4	("3469053" "5268548" "5644837" "5725762").PN.	USPAT	2003/03/12 13:13
46	27	encapsulant and encasing and removing and semiconductor near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:19
47	19	("4143456" "4264917" "4300153" "4358552" "4507675" "4642671" "4931852" "4961107" "5101465" "5173764" "5194930" "5379186" "5434105" "5436203" "5450283" "5488254" "5489538" "5489801" "5866953").PN.	USPAT	2003/03/12 13:15
48	0	encapsulant and encasing near removing and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:19
49	0	encapsulant and encasing near removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:19
50	79	encapsulant near removing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:26
51	11	("4460537" "4615857" "4910581" "5417826" "5434750" "5542171" "5557150" "5635671" "5656549" "5780933" "5963792").PN.	USPAT	2003/03/12 13:24
52	14	("4460537" "4615857" "4784974" "4910581" "5417826" "5434750" "5542171" "5557150" "5620928" "5625235" "5635671" "5656549" "5708567" "5756380").PN.	USPAT	2003/03/12 13:25
53	0	"removing said encapsulant"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:30
54	0	encapsulant near grinding and semiconductor near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:31

55	4103	grinding and semiconductor near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:32
56	10	removing and grinding and encapsulant near material and semiconductor near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:35
57	0	20030006494.URPN.	USPAT	2003/03/12 13:34
58	15	grinding and encapsulant near material and semiconductor near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:35
59	33	grinding and encapsulant near material and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/12 13:36
60	8	("5471087" "5773323" "5855727" "5863810" "5897338" "5932061" "6069392" "6136212").PN.	USPAT	2003/03/12 13:39
61	23	("H001379" "3482419" "3627901" "3762039" "3969813" "4089704" "4359360" "4384917" "4474621" "4567006" "4691225" "4768286" "4914813" "4980019" "5041396" "5138430" "5149662" "5155068" "5180093" "5252179" "5398926" "5406117" "5424254").PN.	USPAT	2003/03/12 13:46
62	19	5424254.URPN.	USPAT	2003/03/12 13:49